# RHRP860-F085



# 8A,600V Hyperfast Diodes

The RHRP860-F085 is hyperfast diodes with soft recovery characteristics ( $t_{rr}$  < 30ns). It has half the recovery time of ultrafast diodes and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as

freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49059.

# **Ordering Information**

PART NUMBER	PACKAGE	BRAND	
RHRP860-F085	TO-220AC	RHRP860-F085	

NOTE: When ordering, use the entire part number.

# Symbol



# Features

- Hyperfast with Soft Recovery.....

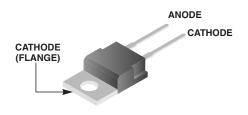
- Avalanche Energy Rated
- Planar Construction

# Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

# Packaging

#### JEDEC TO-220AC



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### Absolute Maximum Ratings $T_C = 25^{\circ}C$ , Unless Otherwise Specified

	RHRP860-F085	UNITS	
Peak Repetitive Reverse Voltage	600	V	
Working Peak Reverse Voltage	600	V	
DC Blocking Voltage	600	V	
Average Rectified Forward Current I <sub>F(AV)</sub> (T <sub>C</sub> = 150 <sup>o</sup> C)	8	А	
Repetitive Peak Surge CurrentIFRM (Square Wave, 20kHz)	16	А	
Nonrepetitive Peak Surge Current I <sub>FSM</sub> (Halfwave, 1 Phase, 60Hz)	100	А	
Maximum Power Dissipation	75	W	
Avalanche Energy (See Figures 10 and 11)E <sub>AVL</sub>	20	mJ	
Operating and Storage Temperature	-65 to 175	°C	

SYMBOL	TEST CONDITION	MIN	ТҮР	MAX	UNITS
VF	I <sub>F</sub> = 8A	-	-	2.1	V
	I <sub>F</sub> = 8A, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	1.7	V
Ι <sub>R</sub>	V <sub>R</sub> = 400V	-	-	-	μA
	V <sub>R</sub> = 600V	-	-	100	μΑ
	V <sub>R</sub> = 400V, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	-	μA
	V <sub>R</sub> = 600V, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	500	μΑ
t <sub>rr</sub>	$I_{F} = 1A, dI_{F}/dt = 200A/\mu s$	-	-	30	ns
	I <sub>F</sub> = 8A, dI <sub>F</sub> /dt = 200A/μs	-	-	35	ns
t <sub>a</sub>	$I_{F} = 8A, dI_{F}/dt = 200A/\mu s$	-	18	-	ns
t <sub>b</sub>	$I_{F} = 8A, dI_{F}/dt = 200A/\mu s$	-	10	-	ns
Q <sub>RR</sub>	$I_{F} = 8A, dI_{F}/dt = 200A/\mu s$	-	56	-	nC
CJ	V <sub>R</sub> = 10V, I <sub>F</sub> = 0A	-	25	-	pF
R <sub>θJC</sub>		-	-	2	°C/W

### **Electrical Specifications** $T_C = 25^{\circ}C$ , Unless Otherwise Specified

DEFINITIONS

 $V_F$  = Instantaneous forward voltage (pw = 300µs, D = 2%).

I<sub>R</sub> = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a$  +  $t_b$ .

 $t_a$  = Time to reach peak reverse current (See Figure 9).

 $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 9).

Q<sub>RR</sub> = Reverse recovery charge.

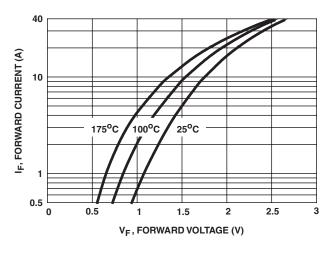
CJ = Junction capacitance.

 $R_{\theta JC}$  = Thermal resistance junction to case.

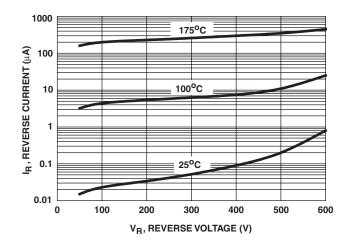
pw = Pulse width.

D = Duty cycle.

# **Typical Performance Curves**







#### FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

# Typical Performance Curves (Continued)

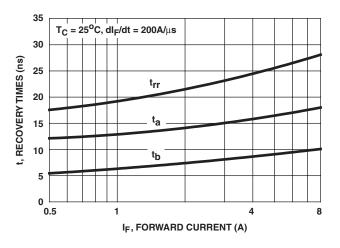
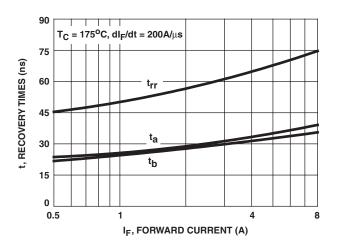


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT





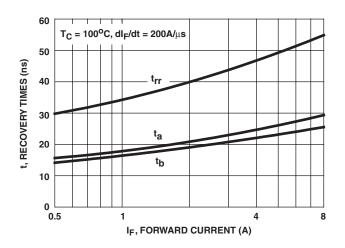


FIGURE 4. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT

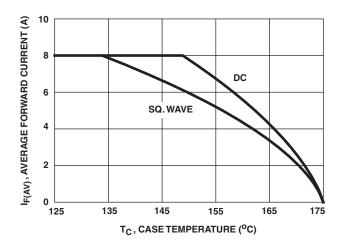


FIGURE 6. CURRENT DERATING CURVE

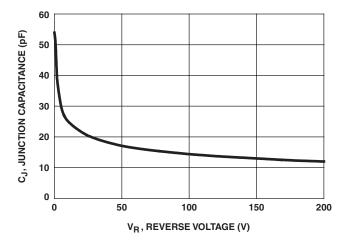
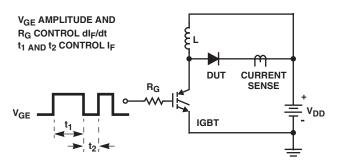


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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# Test Circuits and Waveforms





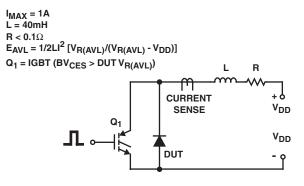


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

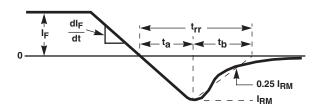


FIGURE 9. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

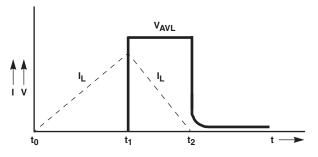


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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